Supporting Information

Comprehensive Physicochemical and Photovoltaic analysis of Different Zn Substitutes (Mn, Mg, Fe, Ni, Co, Ba, Sr) in CZTS-inspired Thin Films Solar Cells

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Figure S1 Plan-view SEM images of CXTS films where a) CZTS, b) CMnTS, c) Mg + CTS, d) Ni + CTS, e) CFeTS, f) CCoTS, g) CBaTS and h) CSrTS.



Figure S2 Grain size distribution for CXTS thin films based on area (top) and diameter (bottom)

Local EDS at large grain surface		Local EDS at small grain surface	
Spectrum 27	Flectron Image 1	"Spectrum 26	Electron Image 1
Spectrum 27 Spectrum 28 Spectrum 28 Spect		Spectrum 28 Spectrum 28 0 2 4 6 8 10 12 14 16 18 20 Full Scale 2486 cts Cursor: 0.000 keV	
Element	Weight% Atomic%	Element	Weight% Atomic%
S K Cu K Sr L Sn L	30.4455.1014.0112.8028.4418.8427.1113.26	S K Cu K Sr L Sn L	41.8365.1028.8522.66-0.62-0.3529.9412.59
Totals	100.00	Totals	100.00

Figure S3 Local EDS measurement for CSrTS at large grains area (left) and small grains area (right)









Figure S4 XRD pattern of CXTS films with each respective reference patterns (excluding CMgTS, no reference available).



Figure S5 a) Normalized XRD peaks for CXTS compounds at 27° - 30°, b) Peak shift toward lower angle for tetragonal phase from smallest to largest ionic radius; Co²⁺ (0.72 Å), Zn²⁺ (0.74 Å), Fe²⁺ (0.77 Å), and Mn (0.80 Å)



Figure S6 Raman scattering spectra of CXTS compounds measured under 785 nm excitation. The reference Raman spectra of monoclinic Cu_2SnS_3 compound is added for convinience.



Figure S7 Raman scattering spectra of CXTS compounds with dominant quaternary phase measured under 532 nm show in the way to maximize the low intensity peaks. Numbers indicate the positions of the well pronounced peaks in the spectra.



Figure S8 Tauc plot for band gap measurements based on UV-Vis spectroscopy



Figure S9 Device parameters for non-stoichiometric (Cu-poor and X-rich) CXTS solar cells as a function of X cations with respect to CZTS reference. The square box inside the box indicates the mean value.



Figure S10 Device parameters for stoichiometry CXTS solar cell as a function of X cations. The square inside box indicate mean value.



Figure S11 Photoluminescence spectra of a) CZTS, b) CMnTS, c) Mg + CTS, d) CBaTS and e) CSrTS